

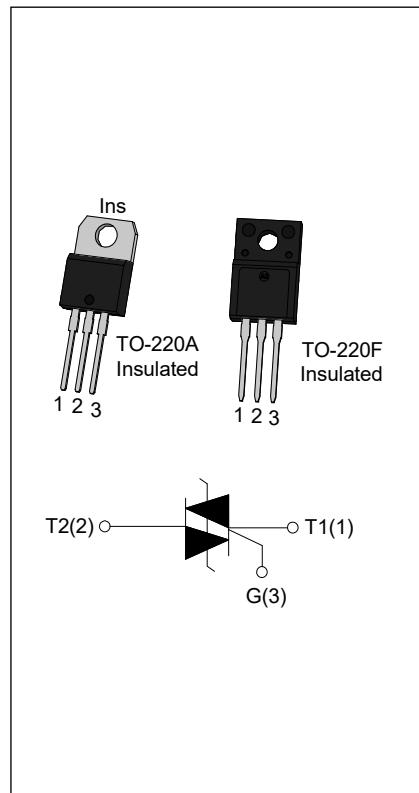


## JST12 Series 12A TRIACs

Rev.6.0

## DESCRIPTION:

JST12 series provide high dv/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on home appliances such as motor control of washing machine. JST12i provides insulation voltage rated at 2500V<sub>RMS</sub> and JST12X provides insulation voltage rated at 2000V<sub>RMS</sub>, from all three terminals to external heatsink complying with UL standards (File ref:E252906). Package TO-220A & TO-220F are RoHS compliant. (2011/65/EU)



## MAIN FEATURES

Symbol	Value	Unit
I <sub>T(RMS)</sub>	12	A
V <sub>DRM</sub> / V <sub>RRM</sub>	800	V

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T <sub>stg</sub>	-40-150	°C
Operating junction temperature range	T <sub>j</sub>	-40-125	°C
Repetitive peak off-state voltage( T <sub>j</sub> =25°C)	V <sub>DRM</sub>	800	V
Repetitive peak reverse voltage( T <sub>j</sub> =25°C)	V <sub>RRM</sub>	800	V
RMS on-state current TO-220A (Ins)/ TO-220F (Ins) (T <sub>C</sub> =70°C)	I <sub>T(RMS)</sub>	12	A
Non repetitive surge peak on-state current ( full cycle, F=50Hz)	I <sub>TSM</sub>	120	A
I <sup>2</sup> t value for fusing ( tp=10ms)	I <sup>2</sup> t	72	A <sup>2</sup> s
Rate of rise of on-state current (I <sub>G</sub> =2×I <sub>GT</sub> )	dI/dt	100	A/μs
Peak gate current	I <sub>GM</sub>	4	A

Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	5	W
Peak pulse voltage ( $T_j=25^\circ\text{C}$ ; non-repetitive,off-state;FIG.7)	$V_{PP}$	4	kV

**ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$  unless otherwise specified)**

Symbol	Test Condition	Quadrant		Value			Unit
				SW	CW	BW	
$I_{GT}$	$V_D=12\text{V}$ $R_L=33\Omega$	I - II -III	MAX	10	35	50	mA
$V_{GT}$		I - II -III	MAX	1.3			V
$V_{GD}$	$V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ $R_L=3.3\text{k}\Omega$	I - II -III	MIN	0.2			V
$I_L$	$I_G=1.2I_{GT}$	I -III	MAX	30	50	70	mA
		II		40	60	100	
$I_H$	$I_T=100\text{mA}$		MAX	20	40	60	mA
$dV/dt$	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$		MIN	500	1000	1500	V/ $\mu\text{s}$

**STATIC CHARACTERISTICS**

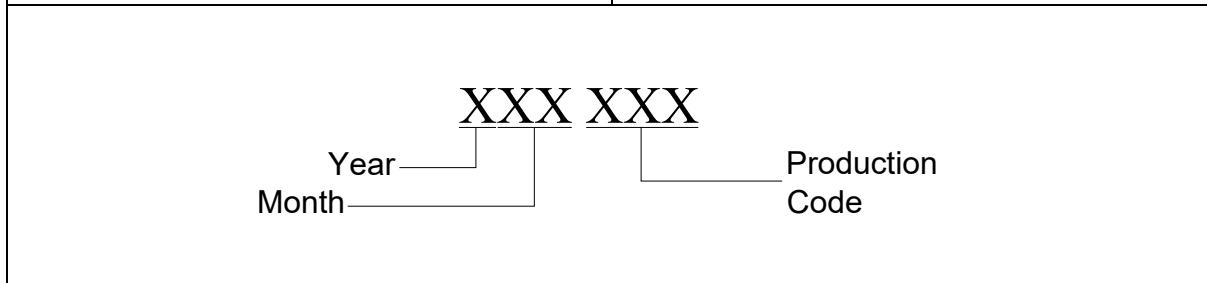
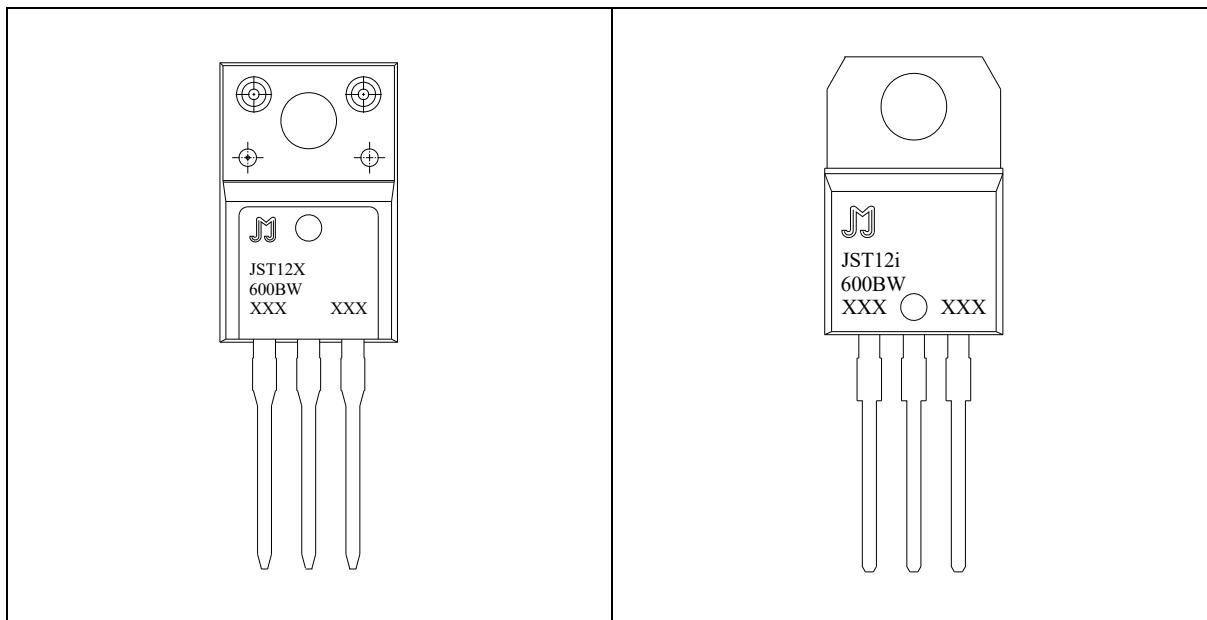
Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM}=18\text{A}$	$t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.5
$V_{TO}$	Threshold voltage		$T_j=125^\circ\text{C}$	0.85
$R_d$	Dynamic resistance		$T_j=125^\circ\text{C}$	35
$I_{DRM}$	$V_D=V_{DRM}$ $V_R=V_{RRM}$		$T_j=25^\circ\text{C}$	5
$I_{RRM}$			$T_j=125^\circ\text{C}$	0.5

**THERMAL RESISTANCES**

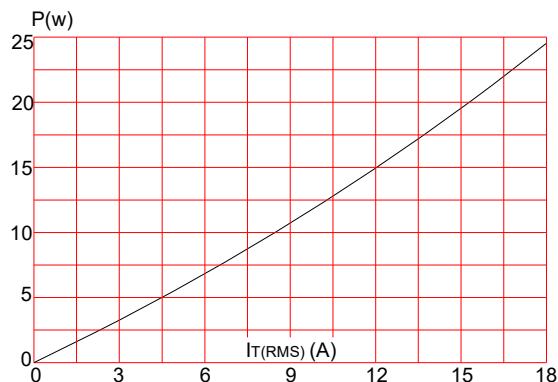
Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-220A Ins	3.4	°C/W
		TO-220F Ins		

**ORDERING INFORMATION**

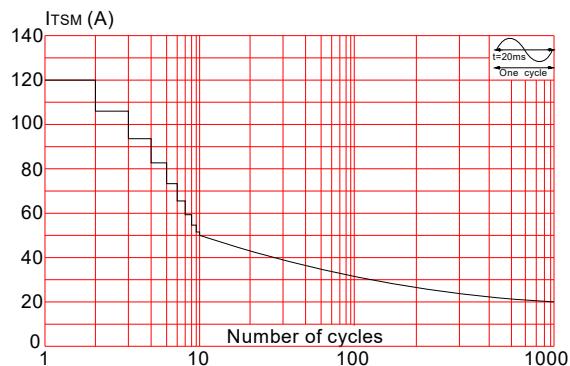
<u>J</u>	<u>ST</u>	<u>12</u>	<u>i</u>	<u>-800</u>	<u>CW</u>	<u>-/</u>
JieJie Microelectronics Co.,Ltd						
	Triacs					
		T(RMS):12A				
			i: TO-220A Ins			
			X:TO-220F Ins			
				800:V <sub>DRM</sub> /V <sub>RRM</sub> ≥800V		
					Blank: Tube	
					SW:IGT1-3≤10mA	
					CW:IGT1-3≤35mA	
					BW:IGT1-3≤50mA	

**MARKING**

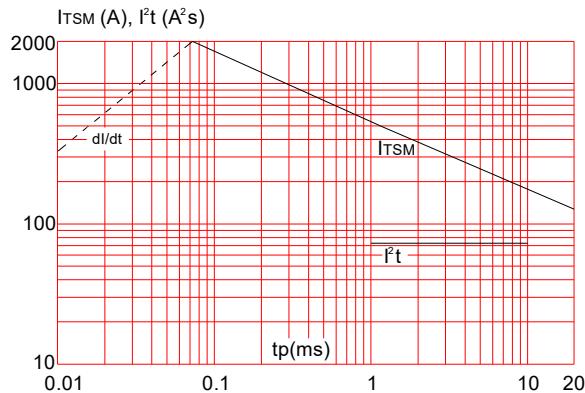
**FIG.1:** Maximum power dissipation versus RMS on-state current



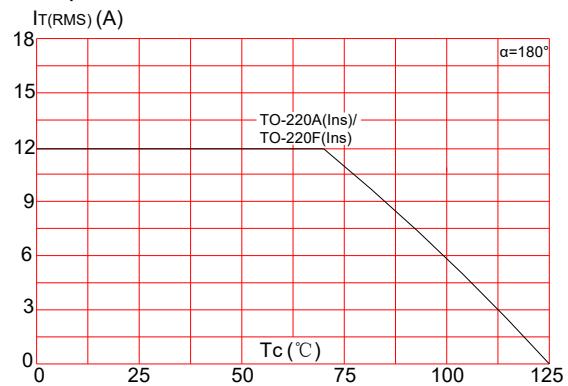
**FIG.3:** Surge peak on-state current versus number of cycles



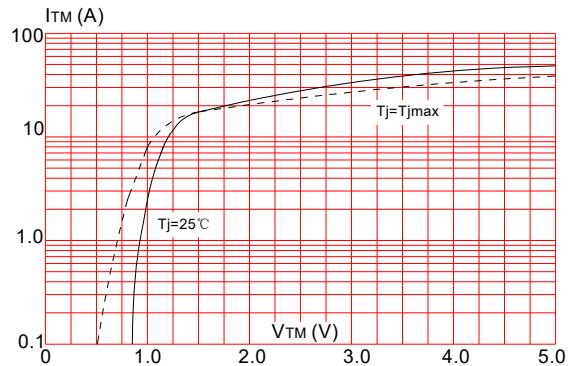
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$  and corresponding value of  $I^2t$  ( $dI/dt < 100\text{A}/\mu\text{s}$ )



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

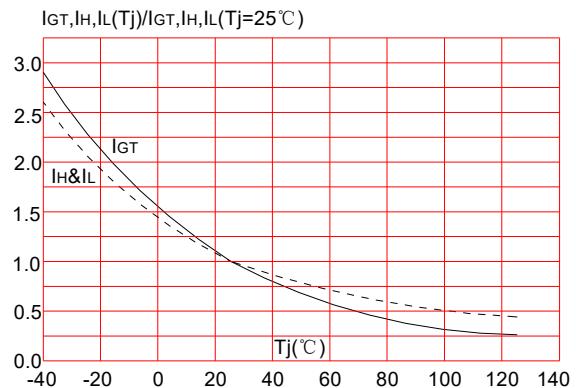
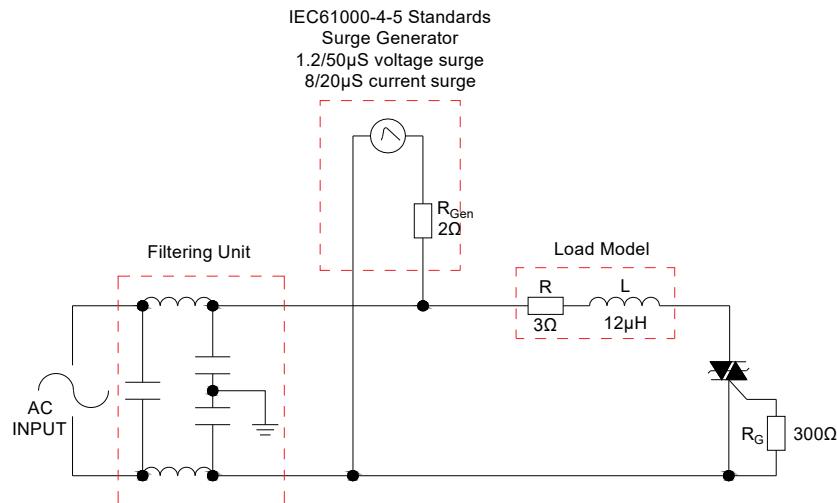


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



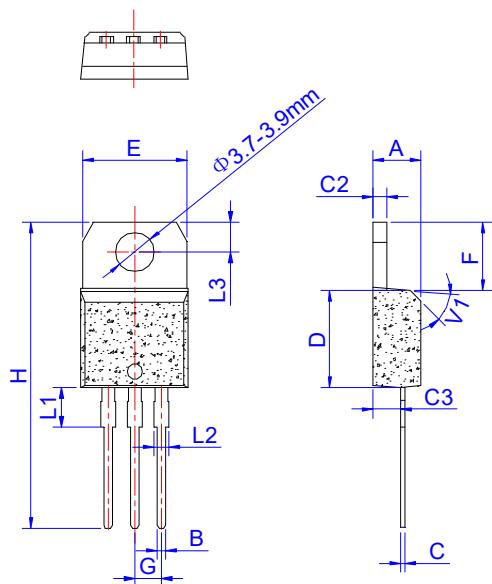
## ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode		
JST12i-800SW	800	10	TO-220A(Ins)	50	Tube		
JST12i-800CW		35					
JST12i-800BW		50					
JST12X-800SW		10	TO-220F(Ins)				
JST12X-800CW		35					
JST12X-800BW		50					

## Document Revision History

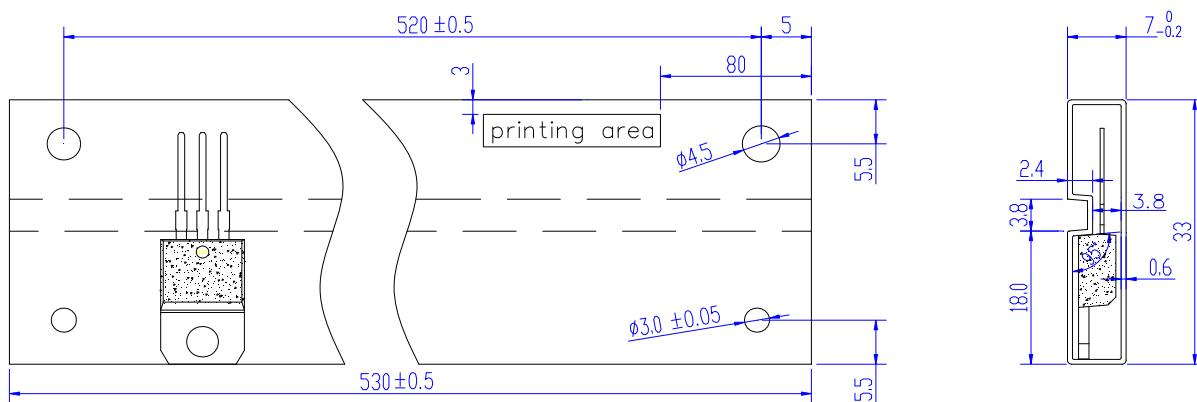
Date	Revision	Changes
Mar 25, 2019	5	Last update
Feb 16, 2022	6	Add Vpp, Vto & Rd value

## PACKAGE MECHANICAL DATA



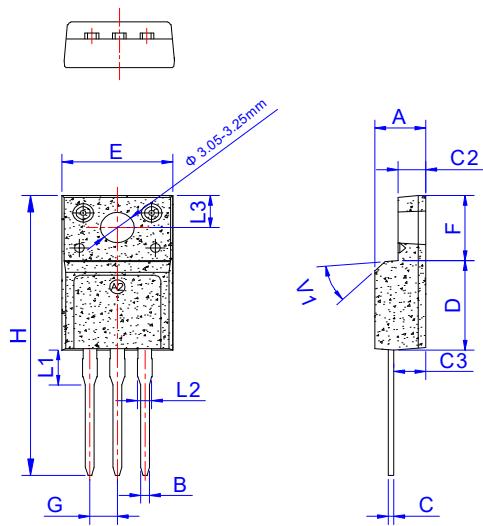
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.25		6.85	0.246		0.270
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.45		4.05	0.136		0.159
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## DELIVERY MODE



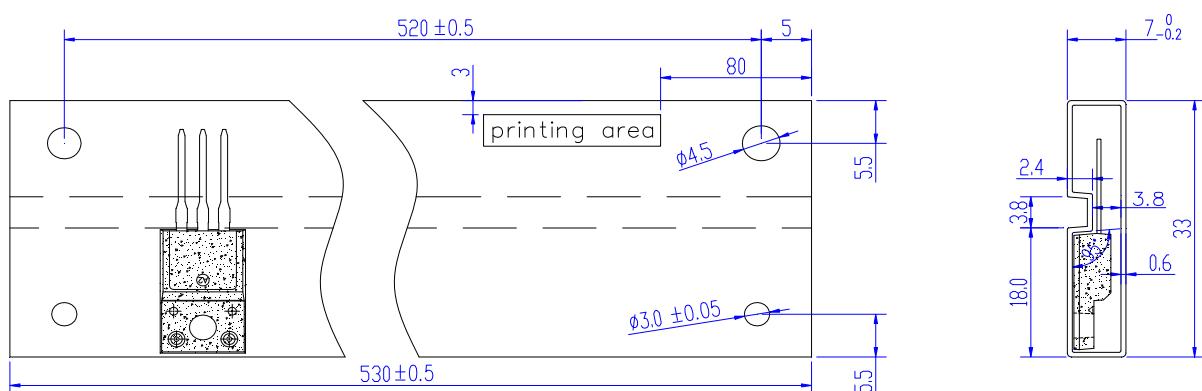
PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220A	TUBE	50	1,000	5,000

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50		4.90	0.177		0.193
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.410
F	6.40		6.80	0.252		0.268
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.20		3.80	0.126		0.150
L2	1.14		1.70	0.045		0.067
L3	3.20		3.60	0.126		0.142
V1		45°			45°	

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220F	TUBE	50	1,000	5,000



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